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✓ OSMM&N File No. 214258US2S

✓ Serial No. 09/956,986

✓ In the matter of the Application of: Michiharu MATSUI et al

✓ For: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE HAVING
ELEMENT ISOLATING REGION OF TRENCH TYPE AND METHOD OF
MANUFACTURING THE SAME

✓ Due Date: 08/09/03

The following has been received in the U.S. Patent Office on the date stamped hereon

- Dep. Acct. Order Form
- ✓ ■ Letter Submitting Drawing Sheet(s)
- ✓ ■ Replacement Drawing 6 sheets
- ✓ ■ Cover/Letter
- ✓ ■ Amendment

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